

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 200 V
CURRENT: 1.0 A

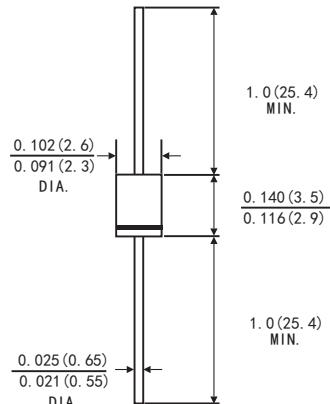
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case : R-1 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026
Polarity: color band denotes cathode end
- Mounting Position : Any
- Weight : 0.007ounce,0.20 gram

R - 1



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

	Symbols	1S20	1S30	1S40	1S50	1S60	1S80	1S100	1S150	1S200	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	57	71	105	140	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see Fig. 1)	I(AV)										Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}										Amps
Maximum instantaneous forward voltage at 1.0 A(Note 1)	V _F		0.55		0.70		0.85	0.90	0.95		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T _A =25°C	IR				0.2					
						10					mA
Typical junction capacitance(Note 3)	C _J					110					pF
Typical thermal resistance(Note 2)	R _{θJA}					50.0					°C/W
Operating junction temperature range	T _J				-65 to +150						°C
Storage temperature range	T _{STG}				-65 to +150						°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance (from junction to ambient)Vertical P.C.B. mounted , 0.5"(12.7mm)lead length

3.Measured at 1.0MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES

1S20 --- 1S200

FIG.1-FORWARD CURRENT DERATING CURVE

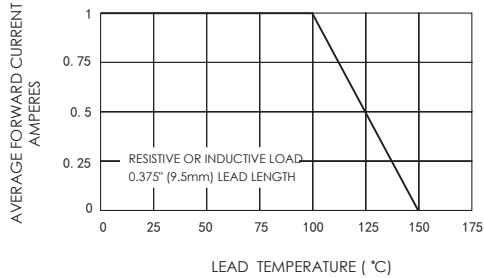


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

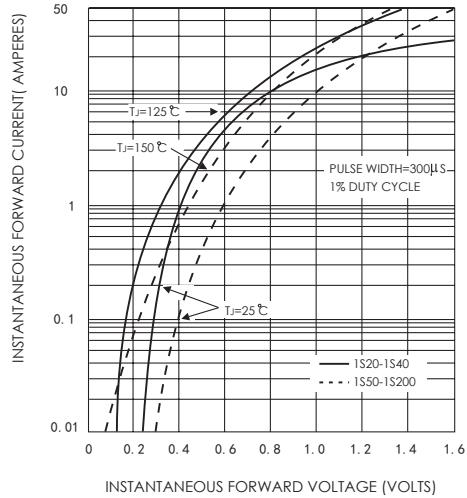


FIG.5-TYPICAL JUNCTION CAPACITANCE

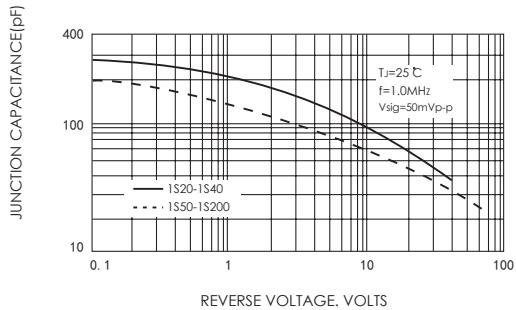


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

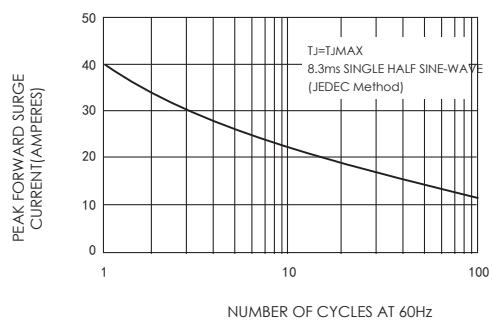


FIG.4-TYPICAL REVERSE CHARACTERISTICS

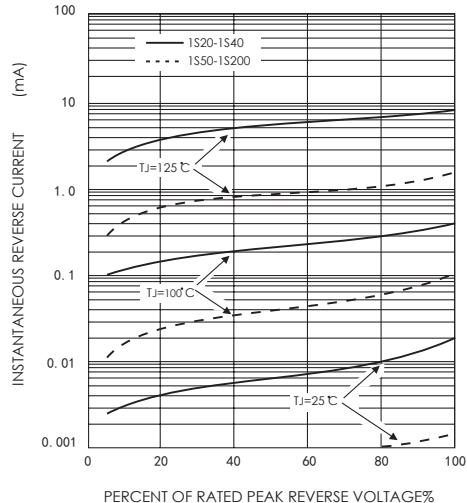


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

